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Substitute Form PTO-1449 U.S. Department of Commerce (Modified) U.S. Department of Commerce Patent and Trademark Office	Attomey's Docket No. 10559-586002	Application No.
Information Disclosure Statement by Applicant	Applicant	
(Use several sheets if necessary) (37 CFR §1.98(b))	Filing Date March 16, 2004	Group Art Unit

U.S. Patent Documents							
Examiner Initial	Desig ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
Sw	. AA	4,848,141	07/1989	Oliver et al.			
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Foreign Patent Documents or Published Foreign Patent Applications								
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Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
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Sw	AK	P.T. Liu et al., Thin Solid Films 332 (1998) 345-350.			
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Examiner Signature	Date Considered
EXAMINER: Initials ditation considered. Draw line through ditation if next communication to applicant.	ot in conformance and not considered. Include copy of this form with
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